## <u>Example: Constructing a</u> <u>Diode Small-Signal Model</u>

Recall that one method for constructing a diode PWL model is to specify a single point (i.e., the **bias point**) on the junction diode curve, and then determine the **slope** of the junction diode curve at that point.

We can then select our **PWL model parameters**  $r_d$  and  $V_{DO}$  such that the PWL model "line" will **intersect** the specified bias point, and so that the slope of the line will **match** that of the junction diode curve at the bias point.

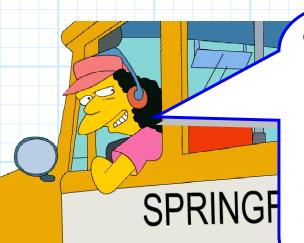
We call this model the small-signal PWL diode model!

For **example**, say a junction diode with n=1 pulls a diode current of  $i_D = 10$  mA at a diode voltage of  $v_D = 0.6$  V.

> Let's build a small-signal PWL model for this diode!

First, we need to select a bias point  $(I_D, V_D)$ . Recall that this can be any point on the junction diode curve.

**Q:** But **which** point do we select? **How** can we decide? A: Remember, a PWL model (with a linear  $i_D, v_D$  relationship) can only "match" the junction diode curve (with an **exponential**  $i_D, v_D$  relationship) over a relatively small region. Thus, we want our PWL model to accurately "match" the junction diode curve over the region where the **correct** junction diode solution  $i_D, v_D$ actually lies.



**Q:** Whoa! How can we do that? We are constructing the PWL model so that we can accurately estimate the **unknown** junction diode values  $i_D$ ,  $v_D$ . But now you say that we must first **know** the solution in order to construct a useful PWL model!

A: It is of course **true** that if we already know the **exact** value of junction diode  $i_D$  and  $v_D$ , we might as well **stop working**—we already have the final answer!

However, we do **not** require the **exact** junction diode solution in order construct a useful PWL model. Rather, we need only to have **approximate** knowledge (i.e., a "rough idea").

Often, we can do a **quick analysis** of a circuit to get a rough ideal of the diode current. For example, we can use the **ideal diode model** (or the **CVD model**) to determine an **approximate** value for  $i_D$ .

You can then use this approximate **current** value to **select your bias point** (on the junction diode curve). Now **you** can construct an accurate small-signal PWL diode model!

OK, now back to our **example**. Say that **somehow** we know that the actual junction diode current in our circuit is in the **vicinity** of 10 mA. Let's therefore use as our bias point the values that we were **initially** given—values that describe a point **lying** on the **junction diode curve**:

$$T_D = 10 \text{ mA}$$
  $V_D = 0.6 \text{ V}$ 

Note that this was the **hardest** part of the whole process! Determining the model parameters is now **straightforward**.

Using the results of a previous handout, we find:

$$r_{d} = \frac{nV_{T}}{I_{D}} = \frac{1(0.025)}{10} = 0.0025 \text{ K} = 2.5 \Omega$$

